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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN THE MATTER OF THE APPLICATION FOR PATENT

OF: Seiji NAKAHATA et al.

ART UNIT: 2812

SERIAL NO.: 10/535,741

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FOR: METHOD OF PROCESSING SURFACE OF NITRIDE SEMICONDUCTOR CRYSTAL AND NITRIDE SEMICONDUCTOR CRYSTAL OBTAINED WITH THE METHOD

COMMISSIONER FOR PATENTS
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November 20, 2006

STATUS REQUEST

Dear Sir:

Please inform us of the status of the processing of this application in the USPTO.

Respectfully submitted
Seiji NAKAHATA et al. - Applicant

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I hereby certify that this correspondence with all indicated enclosures is being deposited with the U. S. Postal Service with sufficient postage as first-class mail, in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date indicated below.

Karin Smith - November 20, 2006
Name: Karin Smith - Date: November 20, 2006